NSN 5962-01-226-4357

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View Online at https://aerobasegroup.com/nsn/5962-01-226-4357

0.840 inches	
Body Width:	
Between 0.220 in	ches and 0.310 inches
Body Height:	
0.185 inches	
Maximum Power	Dissipation Rating:
794.0 milliwatts	
Operating Temp	urature Range:
-55.0/+125.0 degi	ees celsius
Storage Tempur	ature Range:
65.0/+150.0 degi	ees celsius
End Application	
An/bps14to15e	
Features Provide	ed:
Hermetically seale	ed and burn in and programmable and bipolar and schottky
nclosure Materi	al:
Ceramic	
nclosure Config	uration:
Dual-in-line	
Dutput Logic Fo	m:
Fransistor-transis	or logic
nput Circuit Pat	ern:
0 input	
Case Outline So	urce And Designator:
D-2 mil-m-38510	
Terminal Surface	e Treatment:
Solder	
Voltage Rating A	nd Type Per Characteristic:
0.5 volts power:	source and 7.0 volts power source
Time Rating Per	Chacteristic:
-	ds propagation delay time, low to high level output and 85.00 nanoseconds propagation delay time, high to low level
output	
Memory Device	Type:
Prom	
Memory Capacit	<i>I</i> :
Unknown	
Test Data Docun	nent:
	standard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type A	
16 printed circuit	
Shelf Life:	

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Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

A458a0

